

NX5DV330

Quad 1-of-2 video multiplexer/demultiplexer

Rev. 03 — 5 August 2009

Product data sheet

1. General description

The NX5DV330 is a quad 1-of-2 high-speed TTL-compatible video multiplexer/demultiplexer. The low ON resistance of the switch allows inputs to be connected to outputs without adding propagation delay or generating additional ground bounce noise

It has a digital select input (S), four independent inputs/outputs (nY0, nY1), a common input/output (nZ) and an active LOW enable input (\bar{E}). When pin \bar{E} is HIGH, the switch is turned off.

Schmitt-trigger action at the enable input (\bar{E}) and select input (S) makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 4.0 V to 5.5 V.

The NX5DV330 is characterized for operation from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$.

2. Features

- $5\ \Omega$ switch connection between two ports
- TTL-compatible input levels
- Minimal propagation delay through the switch
- ESD protection:
 - ◆ HBM JESD22-A114E Class 2A exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
 - ◆ CDM JESD22-C101C exceeds 1000 V
- Latch-up testing is done to JEDEC standard JESD78 which exceeds 100 mA

3. Ordering information

Table 1. Ordering information

| Type number | Package | | | Version |
|-------------|-------------------|-----------------------|--|----------|
| | Temperature range | Name | Description | |
| NX5DV330D | -40 °C to +85 °C | SO16 | plastic small outline package; 16 leads; body width 3.9 mm | SOT109-1 |
| NX5DV330DS | -40 °C to +85 °C | SSOP16 ^[1] | plastic shrink small outline package; 16 leads; body width 3.9 mm; lead pitch 0.635 mm | SOT519-1 |
| NX5DV330PW | -40 °C to +85 °C | TSSOP16 | plastic thin shrink small outline package; 16 leads; body width 4.4 mm | SOT403-1 |
| NX5DV330BQ | -40 °C to +85 °C | DHVQFN16 | plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm | SOT763-1 |

[1] Also known as QSOP16.

4. Functional diagram

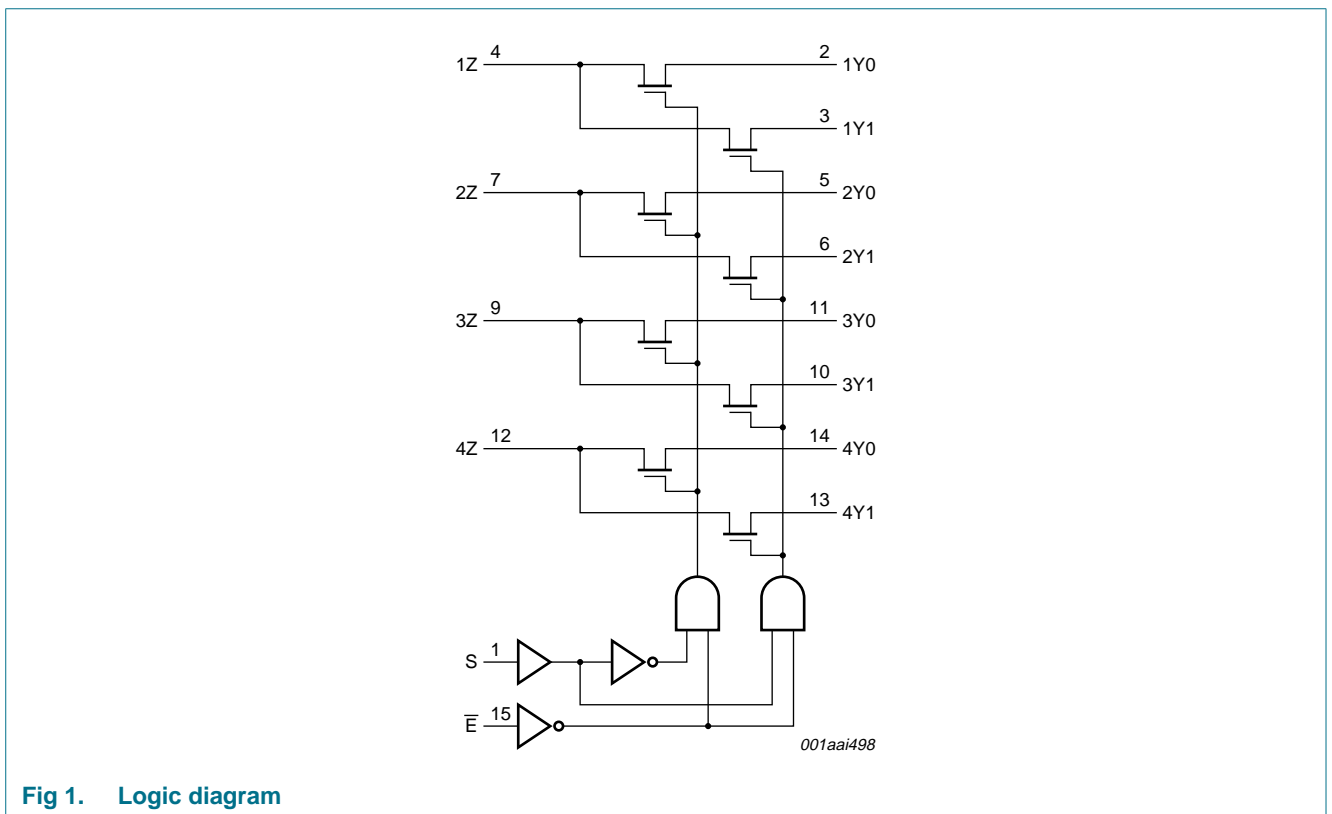


Fig 1. Logic diagram

5. Pinning information

5.1 Pinning

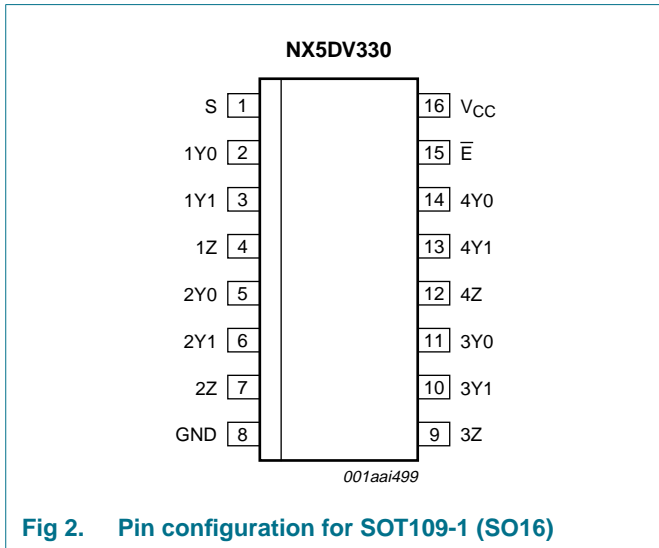


Fig 2. Pin configuration for SOT109-1 (SO16)

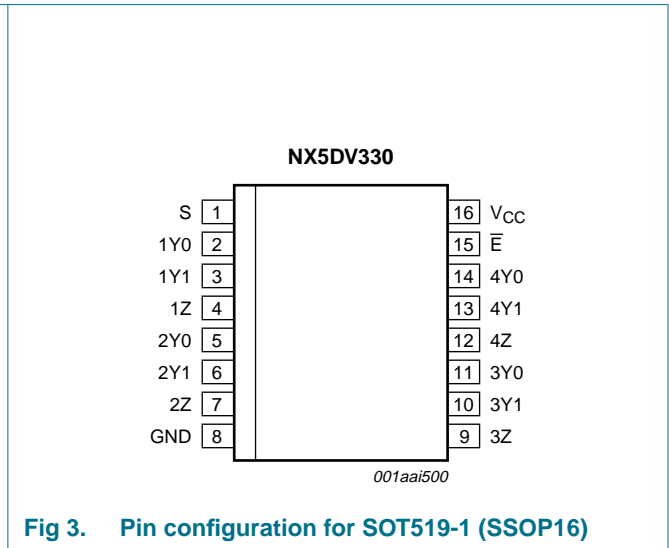


Fig 3. Pin configuration for SOT519-1 (SSOP16)

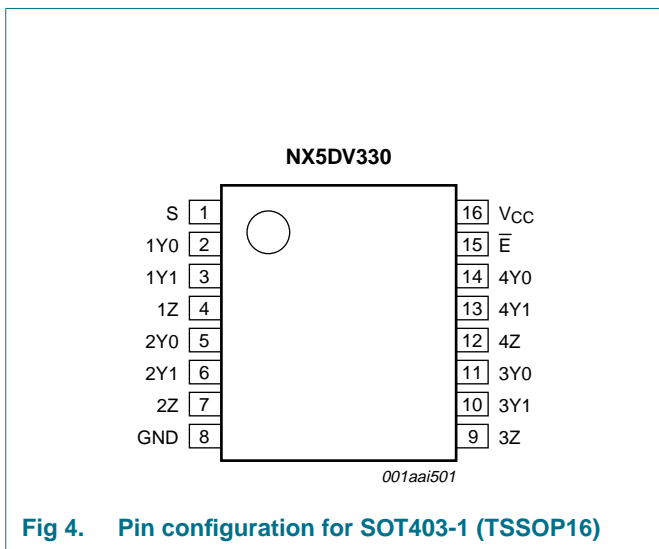


Fig 4. Pin configuration for SOT403-1 (TSSOP16)

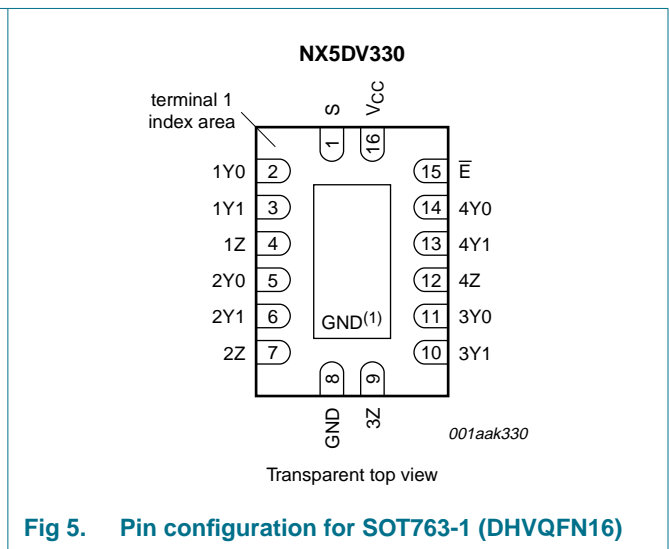


Fig 5. Pin configuration for SOT763-1 (DHWQFN16)

5.2 Pin description

Table 2. Pin description

| Symbol | Pin | Description |
|--|----------------------------|-----------------------------|
| S | 1 | select control input |
| 1Y0, 1Y1, 2Y0, 2Y1, 3Y1, 3Y0, 4Y1, 4Y0 | 2, 3, 5, 6, 10, 11, 13, 14 | independent input or output |
| 1Z, 2Z, 3Z, 4Z | 4, 7, 9, 12 | independent input or output |
| GND | 8 | ground (0 V) |
| \bar{E} | 15 | enable input (active LOW) |
| V _{CC} | 16 | positive supply voltage |

6. Functional description

Table 3. Function selection

H = HIGH voltage level; L = LOW voltage level; X = Don't care.

| Input | | Switch |
|-----------|---|--------------------|
| \bar{E} | S | |
| L | L | Y0 to Z or Z to Y0 |
| L | H | Y1 to Z or Z to Y1 |
| H | X | switch off |

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------|-------------------------|--|-------------|------|------|
| V_{CC} | supply voltage | | -0.5 | +7.0 | V |
| V_I | input voltage | | [1] -0.5 | +7.0 | V |
| I_{SW} | switch current | continuous current through each switch | - | 128 | mA |
| I_{IK} | input clamping current | $V_I < 0$ V | - | -50 | mA |
| T_{stg} | storage temperature | | -65 | +150 | °C |
| P_{tot} | total power dissipation | | [2][3][4] - | 500 | mW |

[1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

[2] For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 °C.

[3] For SSOP16 (QSOP16) and TSSOP16 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C.

[4] For DHVQFN16 packages: above 60 °C derate linearly with 4.5 mW/K.

8. Recommended operating conditions

Table 5. Operating conditions

All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------|--------------------------|-----------------------|-----|-----|-----|------|
| V_{CC} | supply voltage | | 4.0 | 5.0 | 5.5 | V |
| V_{IH} | HIGH-level input voltage | | 2.0 | - | - | V |
| V_{IL} | LOW-level input voltage | | - | - | 0.8 | V |
| V_H | hysteresis voltage | pin S, \bar{E} | - | 45 | - | mV |
| T_{amb} | ambient temperature | operating in free-air | -40 | +25 | +85 | °C |

9. Static characteristics

Table 6. Static characteristics

$T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$.

| Symbol | Parameter | Conditions | Min | Typ ^[1] | Max | Unit |
|-----------------|------------------------------------|---|------------------|--------------------|---------|---------------|
| V_{IK} | input clamping voltage | $V_{CC} = 4.5\text{ V}$; $I_I = -18\text{ mA}$ | - | - | -1.2 | V |
| I_I | input leakage current | pin S, \bar{E} ; $V_{CC} = 5.5\text{ V}$; $V_I = \text{GND}$ or 5.5 V | - | - | ± 1 | μA |
| $I_{S(OFF)}$ | OFF-state leakage current | $V_{CC} = 5.5\text{ V}$; $V_I = \text{GND}$; $V_O = 0\text{ V}$ to 5.5 V | - | - | ± 1 | μA |
| I_{OFF} | power-off leakage current | $V_{CC} = 0\text{ V}$; $V_I = V_O = 0\text{ V}$ to 5.5 V | - | - | ± 1 | μA |
| I_{CC} | supply current | $V_{CC} = 5.5\text{ V}$; $I_O = 0\text{ mA}$; $V_I = V_{CC}$ or GND | - | - | 3 | μA |
| ΔI_{CC} | additional supply current | pin S, \bar{E} ; $V_{CC} = 5.5\text{ V}$; one input at 3.4 V , other inputs at V_{CC} or GND | ^[2] - | - | 2.5 | mA |
| C_I | input capacitance | pin S, \bar{E} ; $V_I = 5\text{ V}$ or 0 V | - | 3.5 | - | pF |
| $C_{io(off)}$ | off-state input/output capacitance | Z port; $V_{CC} = 5\text{ V}$; $V_O = 5\text{ V}$ or 0 V ; $\bar{E} = V_{CC}$ | - | 6.0 | - | pF |
| | | Y port; $V_{CC} = 5\text{ V}$; $V_O = 5\text{ V}$ or 0 V ; $\bar{E} = V_{CC}$ | - | 4.0 | - | pF |
| $C_{io(on)}$ | on-state input/output capacitance | Z port; $V_{CC} = 5\text{ V}$; $V_O = 5\text{ V}$ or 0 V ; $\bar{E} = \text{GND}$ | - | 14 | - | pF |
| R_{ON} | ON resistance | $V_{CC} = 4.5\text{ V}$ | ^[3] | | | |
| | | $V_I = 1.0\text{ V}$; $I_I = 13\text{ mA}$ | - | 3 | 7 | Ω |
| | | $V_I = 2.0\text{ V}$; $I_I = 26\text{ mA}$ | - | 7 | 10 | Ω |

[1] All typical values are measured at $V_{CC} = 5\text{ V}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$.

[2] This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND .

[3] Measured by the voltage drop between the Z and the Y terminals at the indicated current through the switch. ON-state resistance is determined by the lowest voltage of the two (Z or Y) terminals.

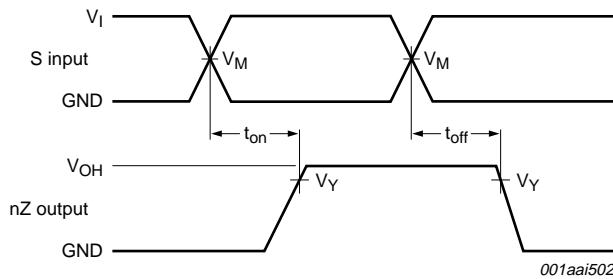
10. Dynamic characteristics

Table 7. Dynamic characteristics

$T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$; for test circuit see [Figure 7](#).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------|---------------|---|-----|-----|-----|------|
| t_{on} | turn-on time | S to nZ; see Figure 6 | | | | |
| | | $V_{CC} = 4.5\text{ V}$ to 5.5 V | - | 4.0 | 6.0 | ns |
| t_{off} | turn-off time | S to nZ; see Figure 6 | | | | |
| | | $V_{CC} = 4.5\text{ V}$ to 5.5 V | - | 2.3 | 6.0 | ns |

11. Waveforms

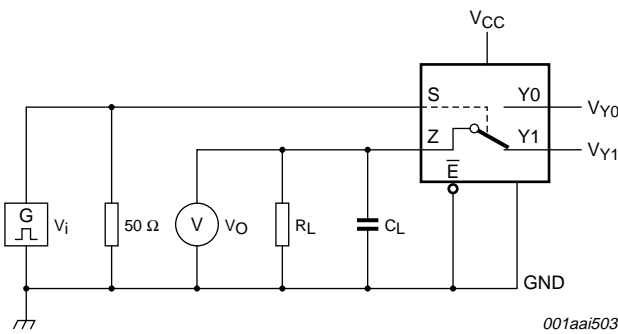


Measurement points are given in [Table 8](#).
 V_{OH} is the typical voltage output level that occurs with the output load.

Fig 6. Input (S) to output (nZ) turn-on and turn-off time

Table 8. Measurement points

| Supply voltage | Input | | Output |
|----------------|--------------|-------|-------------|
| V_{CC} | V_I | V_M | V_Y |
| 4.5 V to 5.5 V | GND to 3.0 V | 1.5 V | $0.9V_{OH}$ |



Test data is given in [Table 9](#).
 Definitions test circuit:
 R_L = Load resistance.
 C_L = Load capacitance including jig and probe capacitance.

Fig 7. Test circuit for measuring turn-on and turn-off times

Table 9. Test data

| Input | | | Load | | | |
|--------------|---------------|---------------|--------------|--------------|-------------|-------|
| V_I | f_i | t_r, t_f | V_{Y0} | V_{Y1} | R_L | C_L |
| GND to 3.0 V | ≤ 10 MHz | ≤ 2.5 ns | GND to 3.0 V | 3.0 V to GND | 75Ω | 20 pF |

12. Additional dynamic characteristics

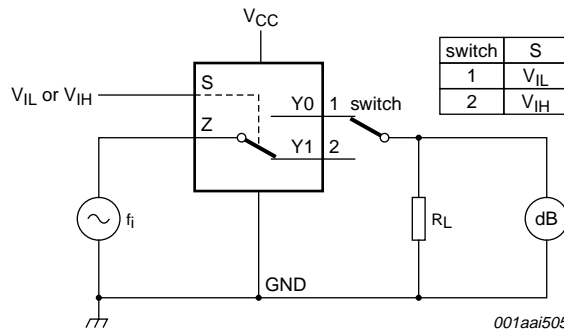
Table 10. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $V_I = GND$ or V_{CC} (unless otherwise specified); $T_{amb} = 25\text{ }^\circ\text{C}$; $V_{CC} = 4.5\text{ V to }5.5\text{ V}$.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------------|--------------------------|---|-----|------|-----|------|
| G_{dif} | differential gain | $f_i = 3.58\text{ MHz}$; $R_L = 150\ \Omega$ | - | 0.64 | - | % |
| ϕ_{dif} | differential phase | $f_i = 3.58\text{ MHz}$; $R_L = 150\ \Omega$ | - | 0.1 | - | deg |
| $f_{(-3dB)}$ | -3 dB frequency response | $R_L = 150\ \Omega$; see Figure 8 | 300 | - | - | MHz |
| α_{iso} | isolation (OFF-state) | $f_i = 10\text{ MHz}$; $R_L = 150\ \Omega$; see Figure 9 | - | -60 | - | dB |
| Xtalk | crosstalk | between switches; see Figure 10 ; $f_i = 10\text{ MHz}$; $R_L = 150\ \Omega$; $R_i = 10\ \Omega$ | [1] | -63 | - | dB |

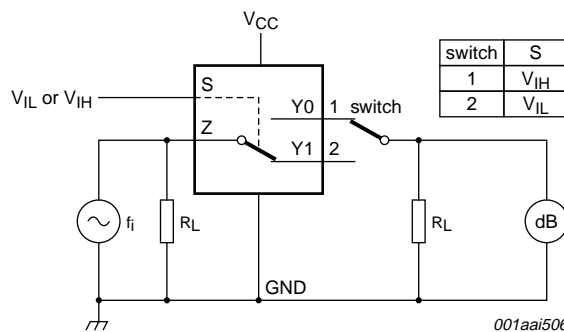
[1] All unused analog input pins (nZ) and outputs pins (nYn) are connected through 10 Ω and 50 Ω pull-down resistors, respectively.

13. Test circuits



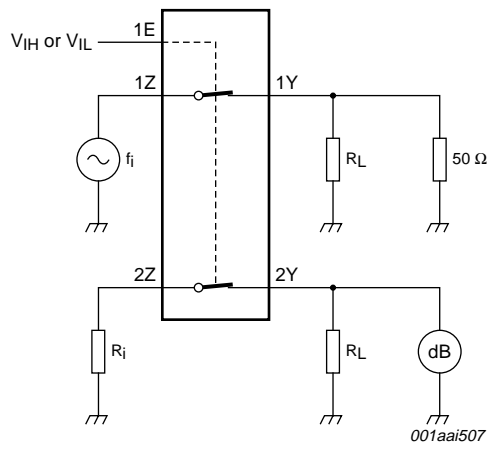
Adjust f_i voltage to obtain 0 dBm level at output. Increase f_i frequency until dB meter reads -3 dB.

Fig 8. Test circuit for measuring the frequency response when channel is in ON-state



Adjust f_i voltage to obtain 0 dBm level at input.

Fig 9. Test circuit for measuring isolation (OFF-state)



Adjust f_i voltage to obtain 0 dBm level at input.

Fig 10. Test circuit for measuring crosstalk voltage between digital inputs and switch

14. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1

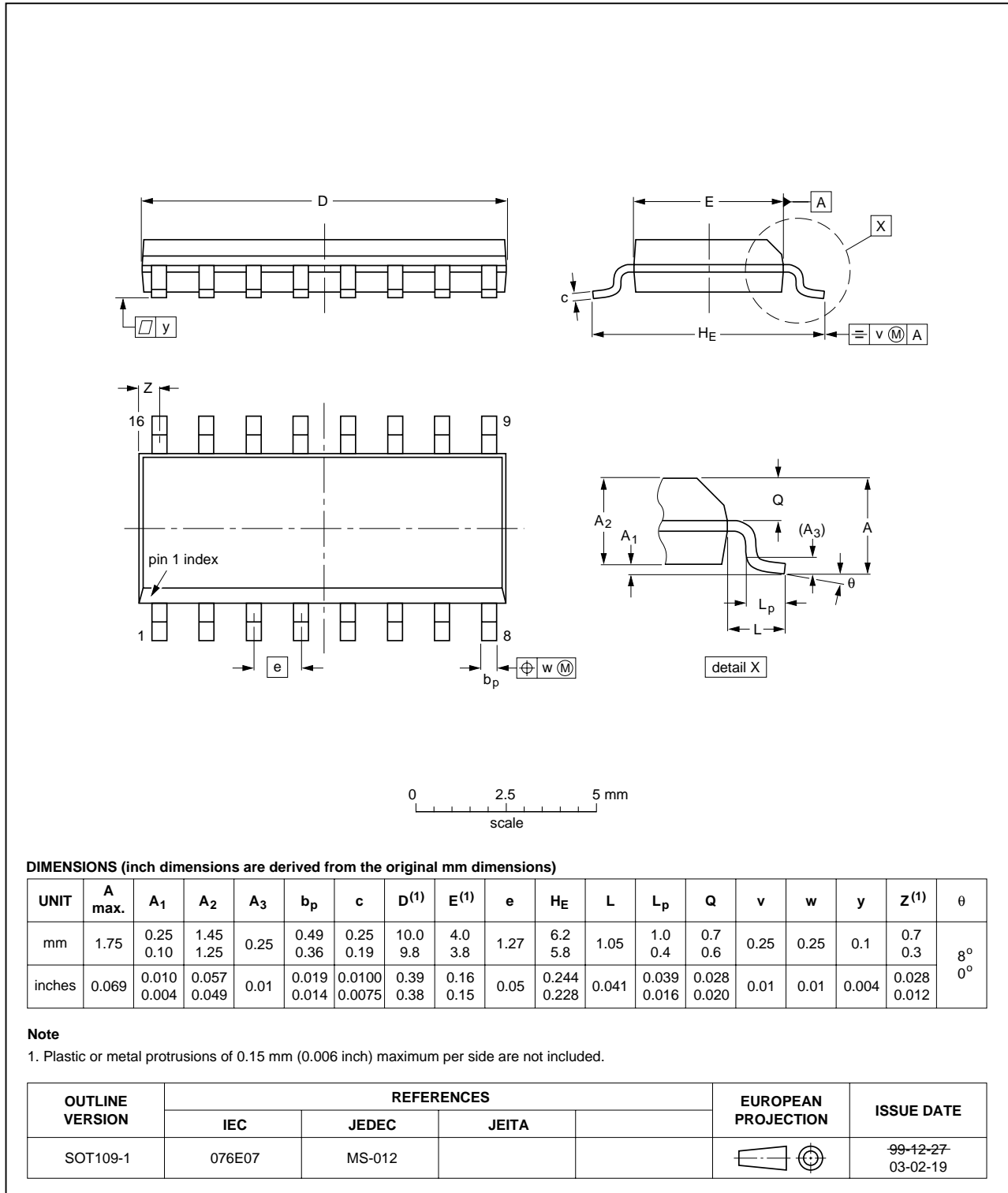


Fig 11. Package outline SOT109-1 (SO16)

SSOP16: plastic shrink small outline package; 16 leads; body width 3.9 mm; lead pitch 0.635 mm SOT519-1

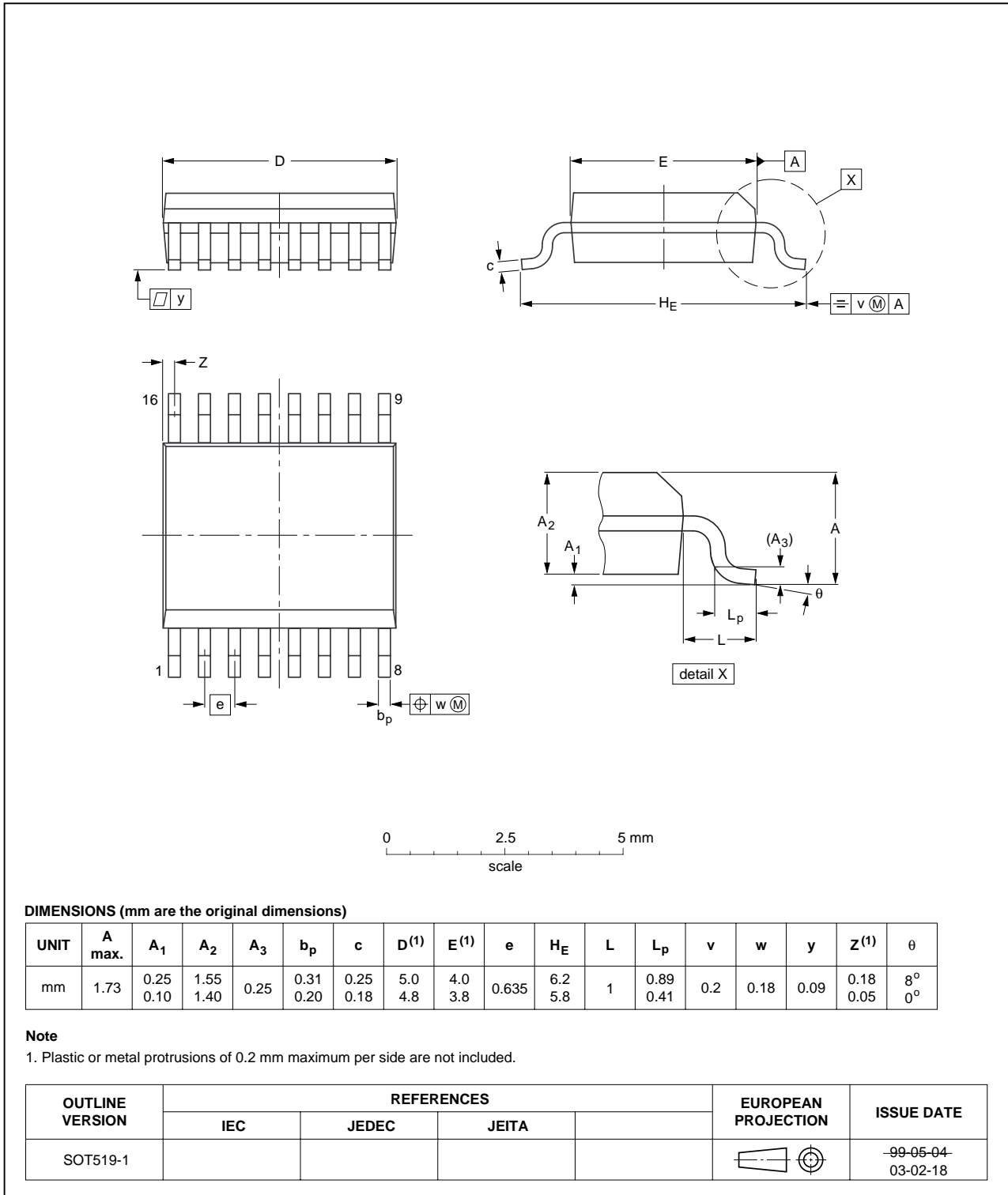


Fig 12. Package outline SOT519-1 (SSOP16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1

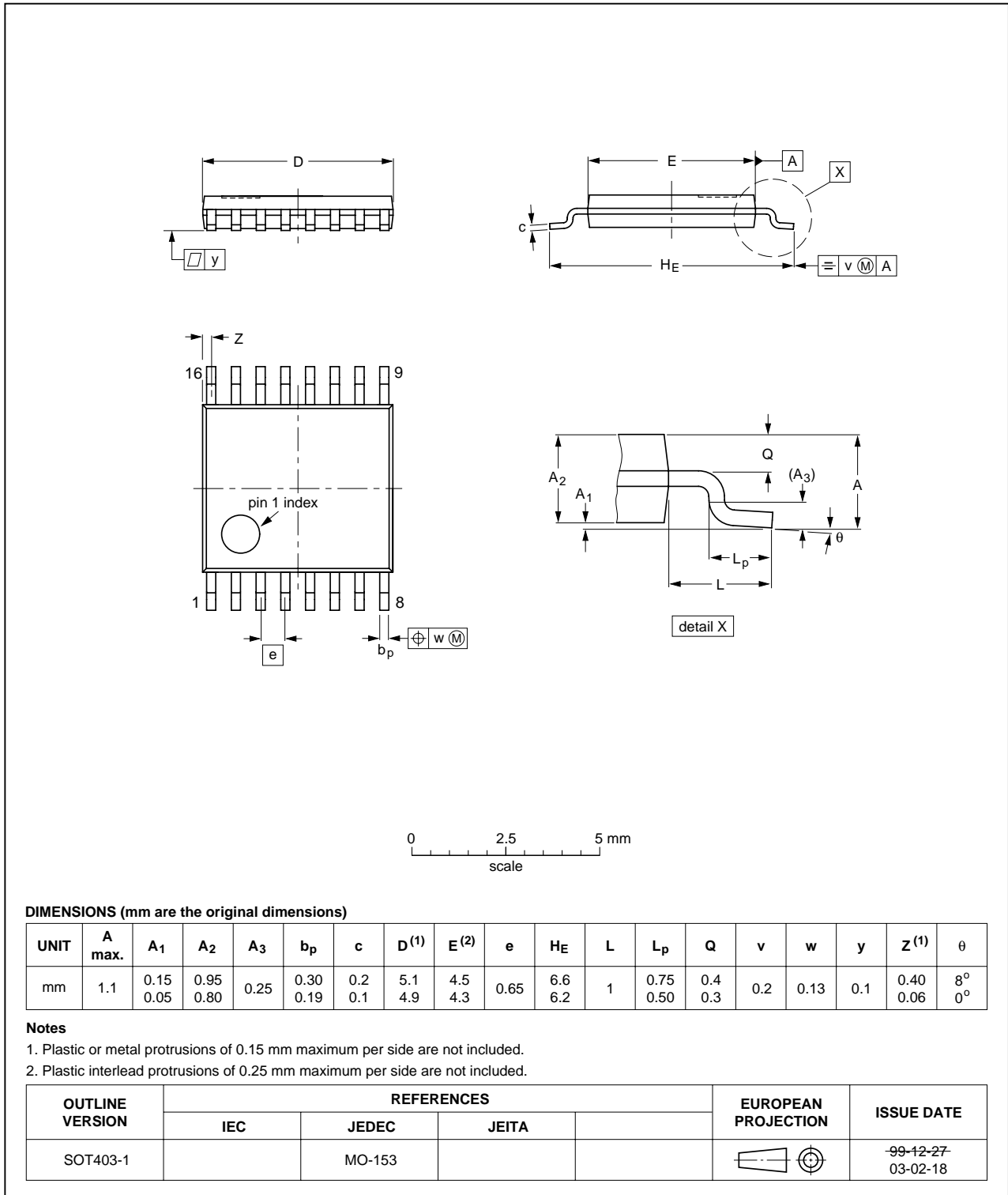


Fig 13. Package outline SOT403-1 (TSSOP16)

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm

SOT763-1

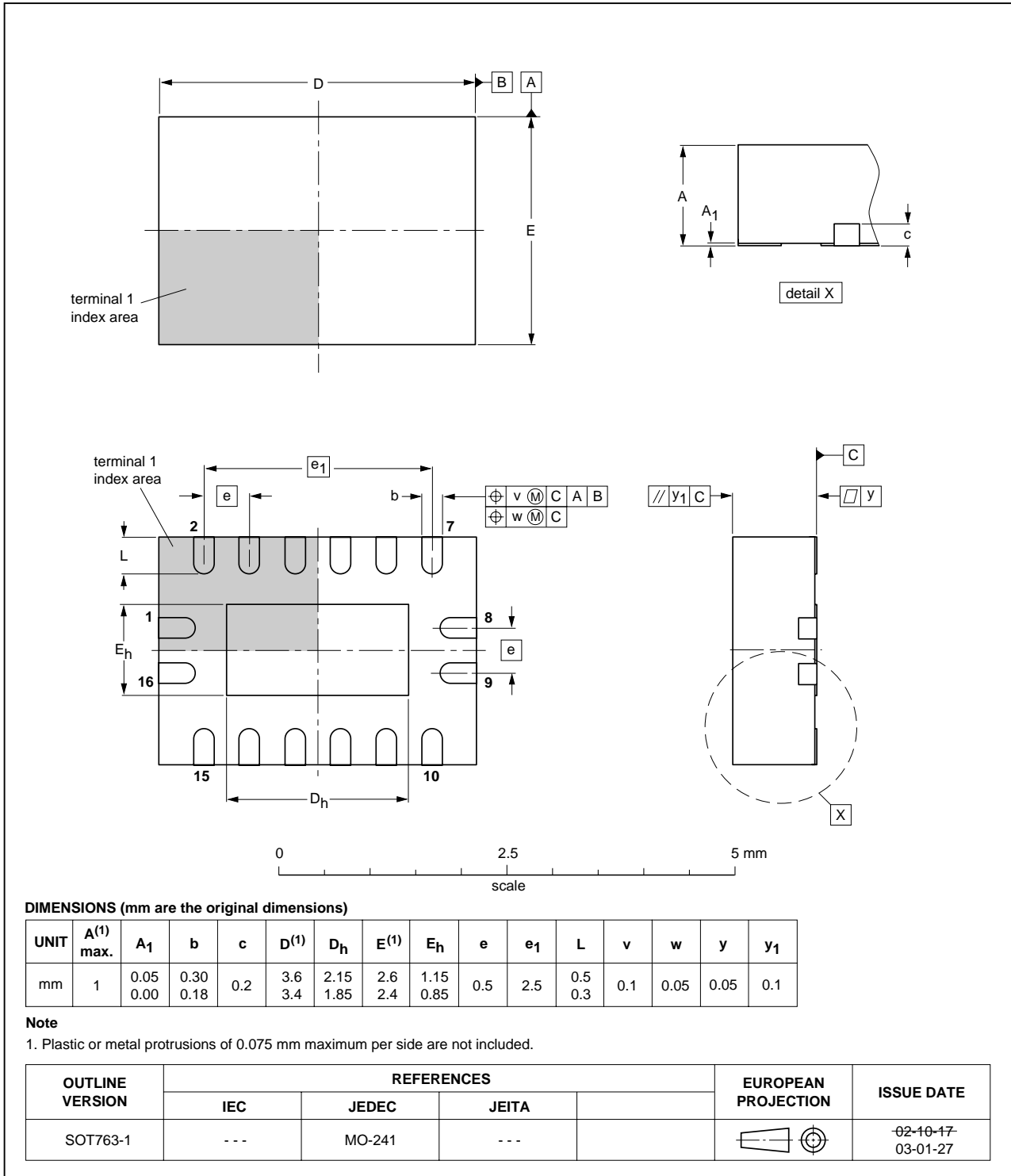


Fig 14. Package outline SOT763-1 (DHVQFN16)

15. Abbreviations

Table 11. Abbreviations

| Acronym | Description |
|---------|-----------------------------|
| CDM | Charged Device Model |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| MM | Machine Model |
| TTL | Transistor-Transistor Logic |

16. Revision history

Table 12. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|---|--------------------|---------------|------------|
| NX5DV330_3 | 20090805 | Product data sheet | - | NX5DV330_2 |
| Modifications: | • Added type number NX5DV330BQ (DHVQFN16 package) | | | |
| NX5DV330_2 | 20080825 | Product data sheet | - | NX5DV330_1 |
| NX5DV330_1 | 20080815 | Product data sheet | - | - |

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| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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